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May 1996



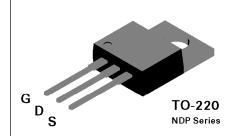
NDP7060 / NDB7060 N-Channel Enhancement Mode Field Effect Transistor

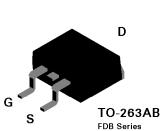
General Description

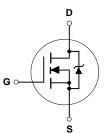
Features

- ver field effect rietary, high cell nsity process is Critical DC electrical parameters specified at elevatedtemperature.
 - Rugged internal source-drain diode can eliminate the need for an external Zener diode transient suppressor.
 - 175°C maximum junction temperature rating.
 - High density cell design for extremely low R_{DS(ON)}.
 - TO-220 and TO-263 (D²PAK) package for both through hole and surface mount applications.

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulses in the avalanche and commutation modes. These devices are particularly suited for low voltage applications such as automotive, DC/DC converters, PWM motor controls, and other battery powered circuits where fast switching, low in-line power loss, and resistance to transients are needed.







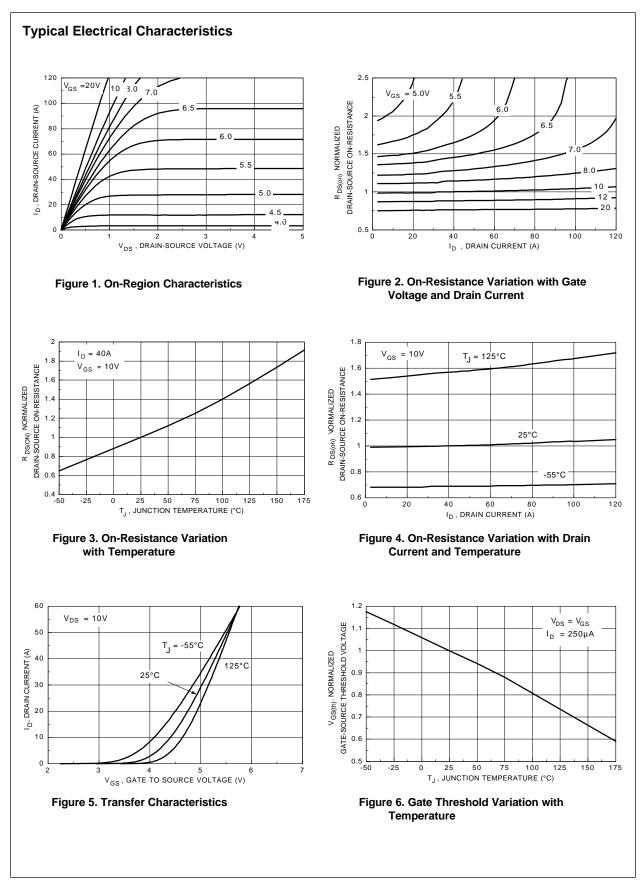
Absolute Maximum Ratings T_c = 25°C unless otherwise noted

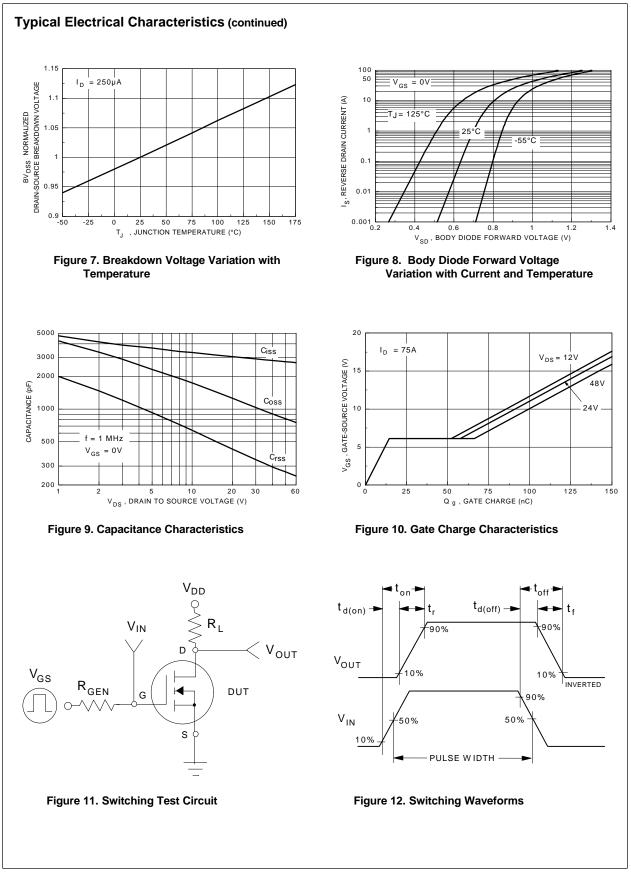
Symbol	Parameter	NDP7060	NDB7060	Units
V _{DSS}	Drain-Source Voltage	60		V
V_{DGR}	Drain-Gate Voltage ($R_{GS} \le 1 \text{ M}\Omega$)	60		V
V _{GSS}	Gate-Source Voltage - Continuous	±20		V
	- Nonrepetitive ($t_p < 50 \ \mu s$)	± 40		
I _D	Drain Current - Continuous	75		А
	- Pulsed	225		
P _D	Maximum Power Dissipation @ $T_c = 25^{\circ}C$	150		
	Derate above 25°C	Derate above 25°C 1		W/°C
T_,T _{stg}	Operating and Storage Temperature Range	-65 to 1	°C	
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	275		°C

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DRAIN-S	OURCE AVALANCHE RATINGS (Note 1)						
W _{DSS}	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 25 \text{ V}, \text{ I}_{D} = 75 \text{ A}$				550	mJ
I _{AR}	Maximum Drain-Source Avalanche Curre	ent				75	Α
OFF CH/	ARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = 250 \ \mu\text{A}$		60			V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	T ₁ = 125°C			250 1	μA mA
	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$	1 _J = 120 0			100	nA
	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$ $V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
	RACTERISTICS (Note 1)	GS, DS _					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$		2	2.8	4	V
			T _{.1} = 125°C	1.4	2.1	3.6	1
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_{D} = 40 \text{ A}$	J		0.01	0.013	Ω
			T _. = 125°C		0.015	0.024	1
I _{D(on)}	On-State Drain Current	V _{GS} = 10 V, V _{DS} = 10 V		75			Α
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 37.5 A		15	39		S
DYNAMI	C CHARACTERISTICS	·					
C _{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz			2960	3600	pF
C _{oss}	Output Capacitance				1130	1600	pF
C _{rss}	Reverse Transfer Capacitance				380	800	pF
	NG CHARACTERISTICS (Note 1)						
t _{D(on)}	Turn - On Delay Time	$V_{DD} = 30 \text{ V}, \ I_{D} = 75 \text{ A},$			17	30	nS
t,	Turn - On Rise Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 5 \Omega$			128	400	nS
t _{D(off)}	Turn - Off Delay Time				54	80	nS
t,	Turn - Off Fall Time				90	200	nS
Q	Total Gate Charge	V _{DS} = 48 V,			100	115	nC
Q _{gs}	Gate-Source Charge	$I_{\rm D}^{\rm US} = 75 \text{A}, V_{\rm GS} = 10 \text{V}$			14.5		nC
Q _{gd}	Gate-Drain Charge				51		nC

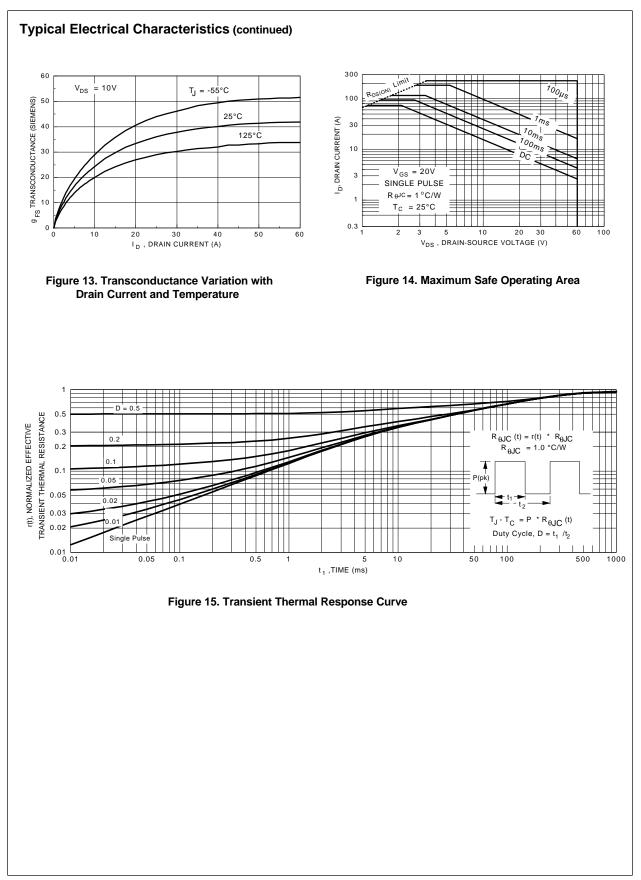
Electric	al Characteristics (T _c = 25°C unless o	therwise noted)					
Symbol	Parameter	Conditions		Min	Тур	Max	Units
DRAIN-S	OURCE DIODE CHARACTERISTICS						•
I _s	Maximum Continuos Drain-Source Diode Forward Current				75	Α	
I _{SM}	Maximum Pulsed Drain-Source Diode Fo	Drain-Source Diode Forward Current				225	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 37.5 \text{ A} \text{ (Note 1)}$			0.9	1.3	V
			T _J = 125°C		0.84	1.2	
t _r	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{F} = 75 \text{ A}, dI_{F}/dt = 100 \text{ A}$	/µs	40	76	150	ns
l _{rr}	Reverse Recovery Current			2	4.7	10	Α
THERMA	L CHARACTERISTICS						•
R _{θJC}	Thermal Resistance, Junction-to-Case					1	°C/W
R _{ØJA}	Thermal Resistance, Junction-to-Ambient				62.5	°C/W	
Note:						•	

Note: 1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.





NDP7060.SAM



NDP7060.SAM

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